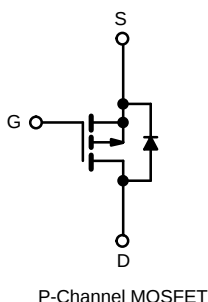
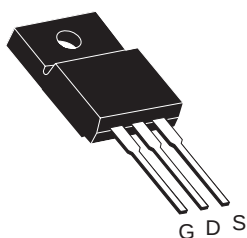


Power MOSFET

V_{DS} (V)	- 200								
$R_{DS(on)}$ (Ω)	$V_{GS} = - 10 \text{ V}$							1.5	
Q_g (Max.) (nC)	15								
Q_{gs} (nC)	3.2								
Q_{gd} (nC)	8.4								
Configuration	Single								

TO-220 FULLPAK



□ □ □ □ □ □ □ □

- Isolated Package
- High Voltage Isolation = 2.5 kV_{RMS} (t = 60 s; f = 60 Hz)
- Sink to Lead Creepage Dist. = 4.8 mm
- P-Channel
- Dynamic dV/dt
- Low Thermal Resistance
- Lead (Pb)-free Available



RoHS*
COMPLIANT

□ □ □ □ □ □ □ □ □ □

Third generation Power MOSFETs from Vishay provide the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost-effectiveness.

The TO-220 FULLPAK eliminates the need for additional insulating hardware in commercial-industrial applications. The molding compound used provides a high isolation capability and a low thermal resistance between the tab and external heatsink. This isolation is equivalent to using a 100 micron mica barrier with standard TO-220 product. The FULLPAK is mounted to a heatsink using a single clip or by a single screw fixing.

	
Package	TO-220 FULLPAK
Lead (Pb)-free	IRFI9620GPbF SiHFI9620G-E3
SnPb	IRFI9620G
	SiHFI9620G

T _C = 25 °C, unless otherwise noted					
PARAMETER			SYMBOL	LIMIT	UNIT
Drain-Source Voltage			V _{DS}	- 200	V
Gate-Source Voltage			V _{GS}	± 20	
Continuous Drain Current	V _{GS} at - 10 V	T _C = 25 °C	I _D	- 3.0	A
		T _C = 100 °C		- 1.9	
Pulsed Drain Current ^a			I _{DM}	- 12	
Linear Derating Factor				0.24	W/°C
Single Pulse Avalanche Energy ^b			E _{AS}	80	mJ
Repetitive Avalanche Current ^a			I _{AR}	- 3.0	A
Repetitive Avalanche Energy ^a			E _{AR}	3.0	mJ
Maximum Power Dissipation	T _C = 25 °C		P _D	30	W
Peak Diode Recovery dV/dt ^c			dV/dt	- 5.0	V/ns
Operating Junction and Storage Temperature Range			T _J , T _{stg}	- 55 to + 150	°C
Soldering Recommendations (Peak Temperature)	for 10 s			300 ^d	
Mounting Torque	6-32 or M3 screw			10	lbf · in
				1.1	N · m

Notes

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11).

b. $V_{DD} = -50$ V, starting $T_J = 25$ °C, $L = 13$ mH, $R_G = 25$ W, $I_{AS} = -3.0$ A (see fig. 12).

c. $I_{SD} \approx 3.9$ A, $dI/dt \approx 95$ A/ μ s, $V_{DD} \approx V_{DS}$, $T_J \approx 150$ °C.

d. 1.6 mm from case.

* Pb containing terminations are not RoHS compliant, exemptions may apply

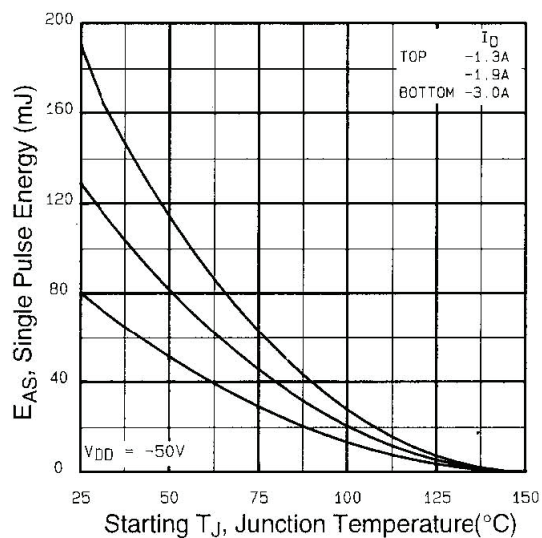


Fig. 12c - Maximum Avalanche Energy vs. Drain Current

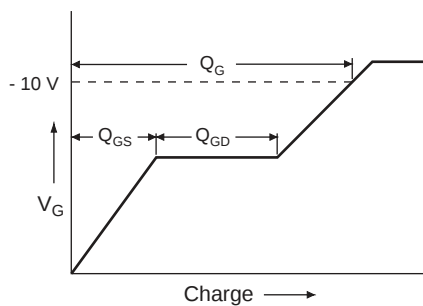


Fig. 13a - Basic Gate Charge Waveform

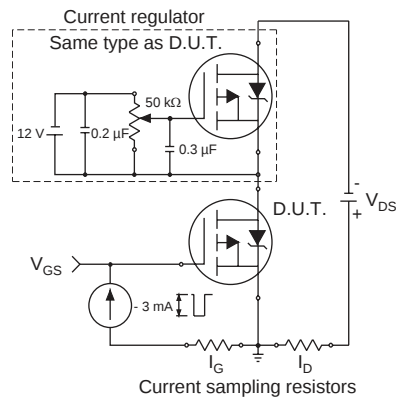
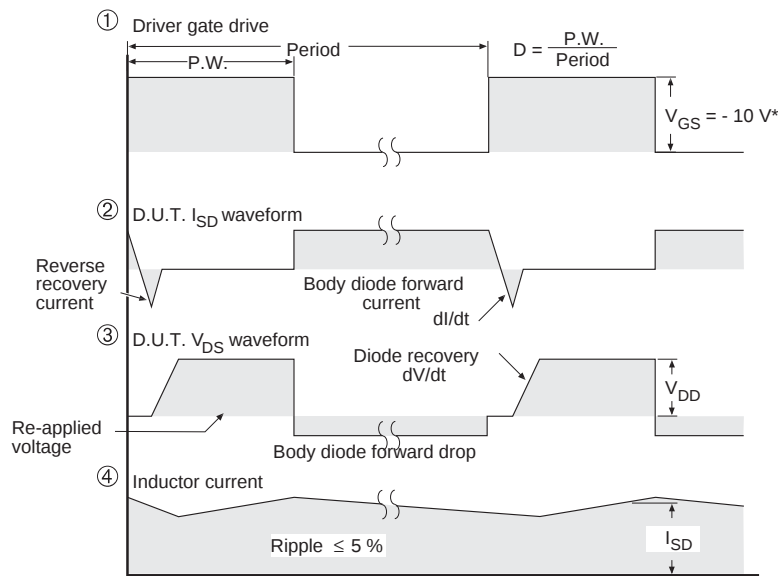
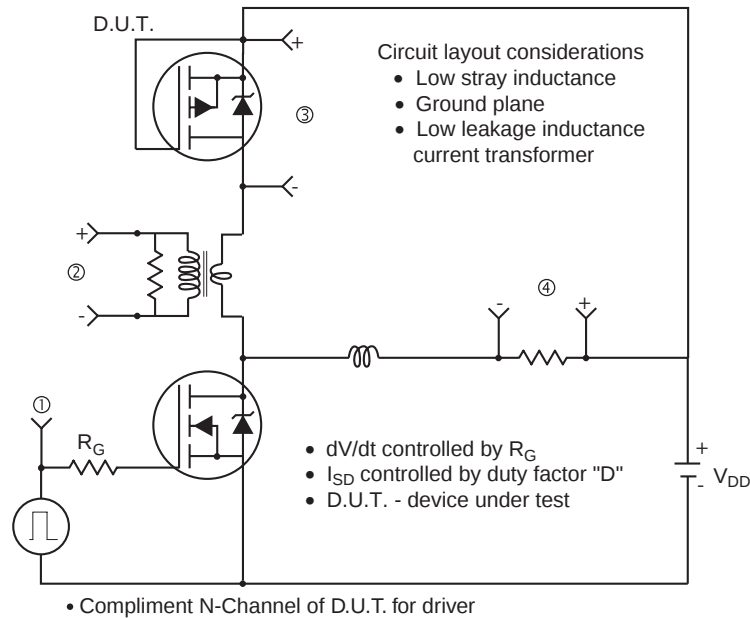


Fig. 13b - Gate Charge Test Circuit

Peak Diode Recovery dV/dt Test Circuit



* $V_{GS} = -5 V$ for logic level and $-3 V$ drive devices

Fig. 14 - For P-Channel

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Электрон
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Наши контакты:

Телефон: +7 812 627 14 35

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Адрес: 198099, Санкт-Петербург,
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